## NSN 5962-01-160-1009



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-160-1009 **Body Length:** 0.430 inches **Body Width:** Between 0.245 inches and 0.285 inches **Body Height:** Between 0.045 inches and 0.090 inches **Maximum Power Dissipation Rating:** 575.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and expandable and w/enable and wire-or outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** F-8 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 140.00 nanoseconds propagation delay time, low to high level output and 140.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 35351-166799 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 flat leads Shelf Life:

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

N/a

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